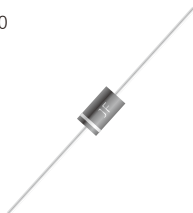
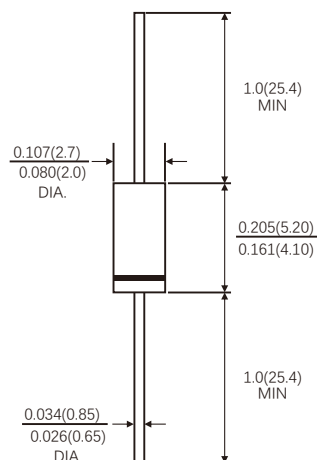


FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2015/863/EU



DO-41



MECHANICAL DATA

- Case: JEDEC DO-41 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD- 750,method 2026
- Polarity: color band denotes cathode end
- Mounting Position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

Parameters		Symbols	SR 220	SR 230	SR 240	SR 260	SR 2100	SR 2150	SR 2200	Units
Maximum repetitive peak reverse voltage		VRRM	20	30	40	60	100	150	200	Volts
Maximum RMS voltage		VRMS	14	21	28	42	71	105	140	Volts
Maximum DC blocking voltage		VDC	20	30	40	60	100	150	200	Volts
Maximum average forward rectified current		I(AV)	2.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)		IFSM	50.0							Amps
Maximum instantaneous forward voltage at 2.0 A(Note 1)		VF	0.55			0.70	0.85	0.90	0.95	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	Tj=25°C	IR	100				20			μA
	Tj=100°C		5.0				-			mA
	Tj=125°C		-				3.0			
Typical junction capacitance(Note 3)		CJ	105			80	60	40		pF
Typical thermal resistance(Note 2)		RθJA RθJL	50.0 15.0							°C/W
Operating junction temperature range		TJ	-55 to+150							°C
Storage temperature range		TSTG	-55 to+150							°C

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle
2.Thermal resistance (from junction to ambient)Vertical P.C.B. mounted , with 1.5X1.5"(38X38mm)copper pads
3.Measured at 1.0MHz and reverse voltage of 4.0 volts

FIG.1-FORWARD CURRENT DERATING CURVE

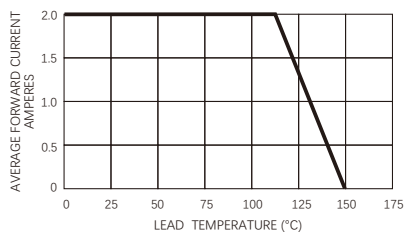


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

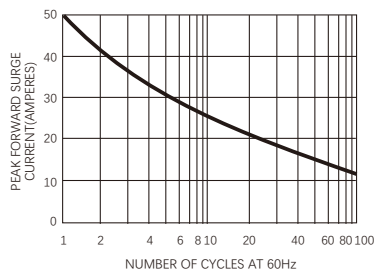


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

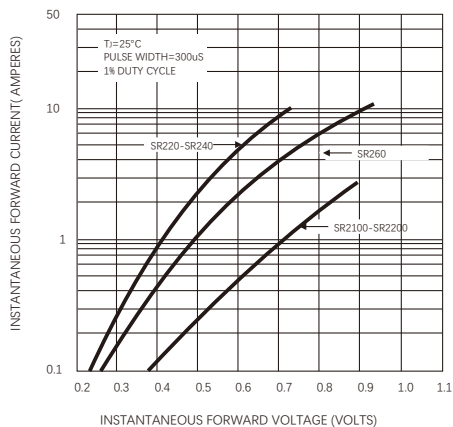


FIG.4-TYPICAL REVERSE CHARACTERISTICS

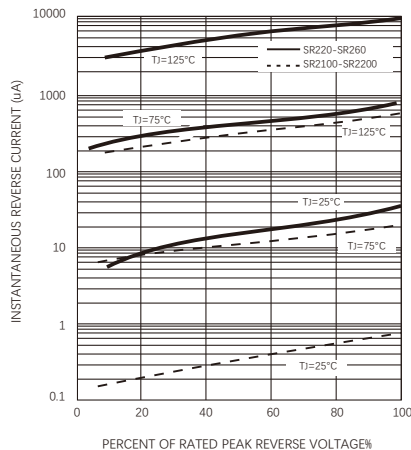
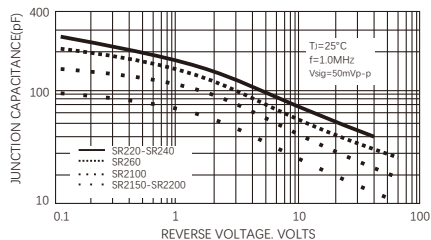


FIG.5-TYPICAL JUNCTION CAPACITANCE



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